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NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE40P70K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge .This device is well suited for high current load applications.

General Features

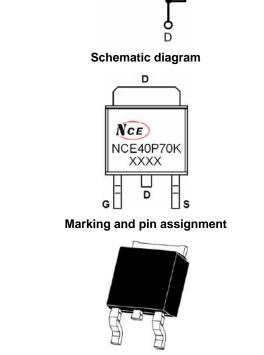
- V_{DS} =-40V,I_D =-70A
 R_{DS(ON)} <10mΩ @ V_{GS}=-10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switch
- Load switch in high current applications
- DC/DC converters

100% UIS TESTED!

100% ΔVds TESTED!



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE40P70K	NCE40P70K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-40	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	-70	А
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	-49.5	A
Pulsed Drain Current	I _{DM}	-200	A
Maximum Power Dissipation	PD	130	W
Derating factor		1.04	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	1012	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C





Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{θJC}	0.96	°C/W
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Electrical Characteristics (T_c=25[°]C unless otherwise noted)

Symbol	Condition	Min	Тур	Max	Unit
		•			
BV _{DSS}	V _{GS} =0V I _D =-250µA	-40	-	-	V
I _{DSS}	V _{DS} =-40V,V _{GS} =0V	-	-	-1	μA
I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
		•			
V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250µA	-1.2	-1.9	-2.5	V
R _{DS(ON)}	V _{GS} =-10V, I _D =-20A	-	7.5	10	mΩ
g fs	V _{DS} =-10V,I _D =-20A	-	50	-	S
•					
C _{lss}		-	5380	-	PF
C _{oss}		-	570	-	PF
C _{rss}	F=1.0MHZ	-	500	-	PF
t _{d(on)}		-	15	-	nS
tr	V_{DD} =-20V, R _L =2 Ω ,	-	12	-	nS
t _{d(off)}	V _{GS} =-10V,R _G =1Ω	-	70	-	nS
t _f		-	18	-	nS
Qg	N/ 001 000	-	106		nC
Q _{gs}		-	22		nC
Q _{gd}	V _{GS} =-10V	-	27		nC
V _{SD}	V _{GS} =0V,I _S =-70A	-		-1.2	V
I _S		-	-	-70	А
t _{rr}				nS	
Qrr	(Nists2)			nC	
	Intrinsic turn-on time is negligible (turn-on is dominated by L				
	Symbol BV _{DSS} I _{DSS} I _{DSS} I _{GSS} V _{GS} (th) R _{DS} (ON) g _{FS} C _{ISS} Q _g Q _g Q _g Q _{gd} V _{SD} I _S t _{rr}	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{tabular}{ c c c c c } \hline Symbol & Condition & Min \\ \hline BV_{DSS} & V_{GS}=0V \ I_D=-250 \mu A & -40 \\ \hline I_{DSS} & V_{DS}=-40V, V_{GS}=0V & - \\ \hline I_{GSS} & V_{GS}=\pm 20V, V_{DS}=0V & - \\ \hline V_{GS(th)} & V_{DS}=V_{GS}, I_D=-250 \mu A & -1.2 \\ \hline V_{GS(th)} & V_{DS}=V_{GS}, I_D=-250 \mu A & -1.2 \\ \hline V_{GS(th)} & V_{GS}=-10V, \ I_D=-20A & - \\ \hline g_{FS} & V_{DS}=-10V, I_D=-20A & - \\ \hline C_{ISS} & V_{DS}=-20V, V_{GS}=0V, \\ \hline C_{Coss} & F=1.0MHz & - \\ \hline C_{ISS} & V_{DS}=-20V, \ R_L=2\Omega, & - \\ \hline t_{d(on)} & V_{GS}=-10V, \ R_G=1\Omega & - \\ \hline t_{f} & V_{DD}=-20V, \ R_L=2\Omega, & - \\ \hline t_{f} & 0 & - \\ \hline Q_{g} & V_{DS}=-20, \ I_D=-20A, & - \\ \hline Q_{gd} & V_{DS}=-20, \ I_D=-20A, & - \\ \hline V_{SD} & V_{GS}=0V, \ I_S=-70A & - \\ \hline I_S & - \\ \hline t_{rr} & TJ = 25^{\circ}C, \ IF =-70A & - \\ \hline \end{tabular}$	$\begin{tabular}{ c c c c c c c } \hline Symbol & Condition & Min & Typ \\ \hline Symbol & V_{GS}=0V \ I_D=-250 \mu A & -40 & - \\ \hline I_{DSS} & V_{DS}=-40V, V_{GS}=0V & - & - \\ \hline I_{GSS} & V_{GS}=\pm 20V, V_{DS}=0V & - & - \\ \hline V_{GS(th)} & V_{DS}=V_{GS}, I_D=-250 \mu A & -1.2 & -1.9 \\ \hline V_{GS(th)} & V_{DS}=V_{GS}, I_D=-20A & - & 7.5 \\ \hline g_{FS} & V_{DS}=-10V, I_D=-20A & - & 50 \\ \hline \hline C_{rss} & V_{DS}=-10V, I_D=-20A & - & 50 \\ \hline \hline C_{rss} & V_{DS}=-20V, V_{GS}=0V, \\ \hline C_{rss} & F=1.0MHz & - & 5380 \\ \hline \hline t_{r} & V_{DD}=-20V, R_L=2\Omega, \\ \hline t_{d(off)} & V_{DS}=-20V, R_L=2\Omega, \\ \hline t_{r} & V_{DS}=-10V, R_G=1\Omega & - & 15 \\ \hline t_{r} & V_{DS}=-20V, R_G=1\Omega & - & 106 \\ \hline Q_{gs} & V_{DS}=-20, I_D=-20A, \\ \hline V_{GS}=-10V & - & 27 \\ \hline \hline V_{SD} & V_{GS}=0V, I_S=-70A & - \\ \hline I_{S} & - & - \\ \hline t_{rr} & TJ = 25^{\circ}C, \ IF =- 70A & - & 53 \\ \hline \end{tabular}$	$\begin{tabular}{ c c c c c c } \hline Symbol & Condition & Min & Typ & Max \\ \hline BV_{DSS} & V_{GS}=0V \ l_{D}=-250 \mu A & -40 & - & - & \\ \hline l_{DSS} & V_{DS}=-40V, V_{GS}=0V & - & - & -1 & \\ \hline l_{GSS} & V_{GS}=\pm 20V, V_{DS}=0V & - & - & \pm 100 & \\ \hline \hline V_{GS(th)} & V_{DS}=V_{GS}, l_{D}=-250 \mu A & -1.2 & -1.9 & -2.5 & \\ \hline R_{DS(ON)} & V_{GS}=-10V, \ l_{D}=-20A & - & 7.5 & 10 & \\ \hline g_{FS} & V_{DS}=-10V, \ l_{D}=-20A & - & 50 & - & \\ \hline \hline C_{1SS} & & V_{DS}=-20V, V_{GS}=0V, & - & 50 & - & \\ \hline \hline C_{1SS} & & V_{DS}=-20V, V_{GS}=0V, & - & 570 & - & \\ \hline \hline C_{1SS} & & V_{DS}=-20V, \ R_{L}=2\Omega, & & - & 570 & - & \\ \hline \hline C_{1SS} & & V_{DS}=-20V, \ R_{L}=2\Omega, & & - & 550 & - & \\ \hline \hline \hline t_{t} & & V_{DD}=-20V, \ R_{L}=2\Omega, & & - & 15 & - & \\ \hline \hline t_{d(off)} & & V_{DS}=-20V, \ R_{G}=1\Omega & & - & 12 & - & \\ \hline \hline t_{t} & & V_{DS}=-20V, \ R_{G}=1\Omega & & - & 18 & - & \\ \hline \hline Q_{q} & & V_{DS}=-20, \ l_{D}=-20A, & & - & 106 & \\ \hline Q_{gs} & & V_{DS}=-20, \ l_{D}=-20A, & & - & 106 & \\ \hline Q_{gs} & & V_{DS}=-20, \ l_{D}=-20A, & & - & 106 & \\ \hline Q_{gs} & & V_{GS}=-10V & & - & 27 & \\ \hline \hline V_{SD} & V_{GS}=0V, \ l_{S}=-70A & - & -1.2 & \\ \hline l_{S} & & - & - & -70 & \\ \hline t_{tr} & \ TJ=25^{\circ}C, \ IF=-70A & - & 53 & \\ \hline \end{tabular}$

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, t \leq 10 sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- **5.** E_{AS} condition: Tj=25 $^\circ C$,V_{DD}=-20V,V_G=-10V,L=1mH,Rg=25\Omega,I_{AS}=45A

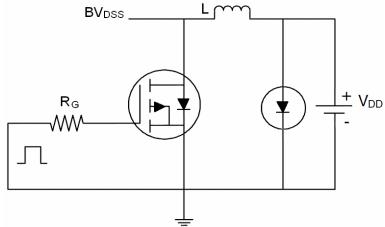


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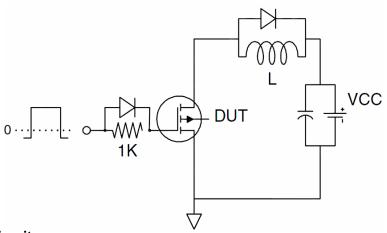
Pb Free Product



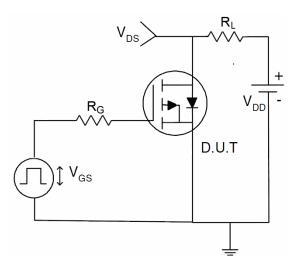
Test Circuit 1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



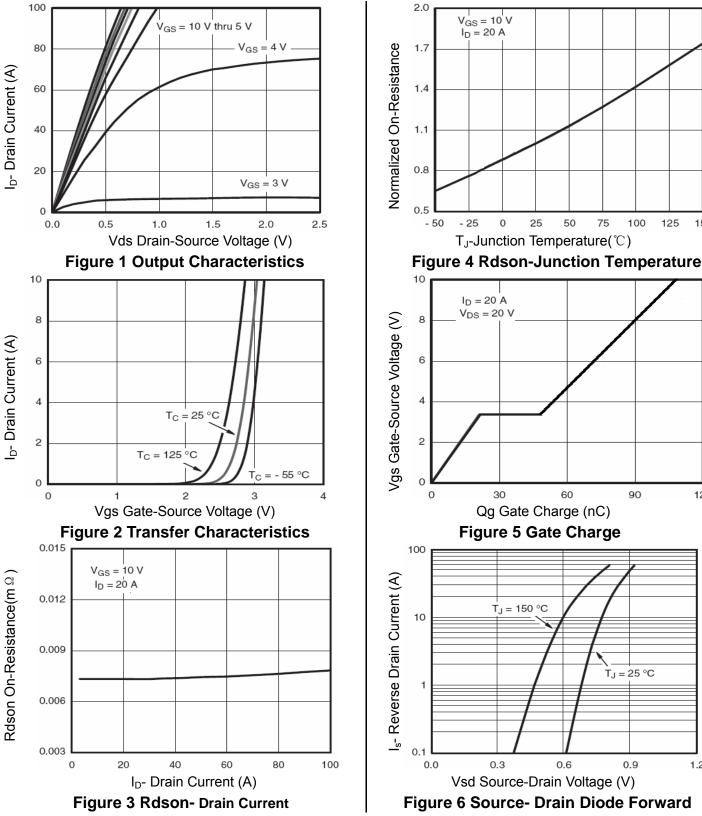




150

120





1.2



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NCE40P70K

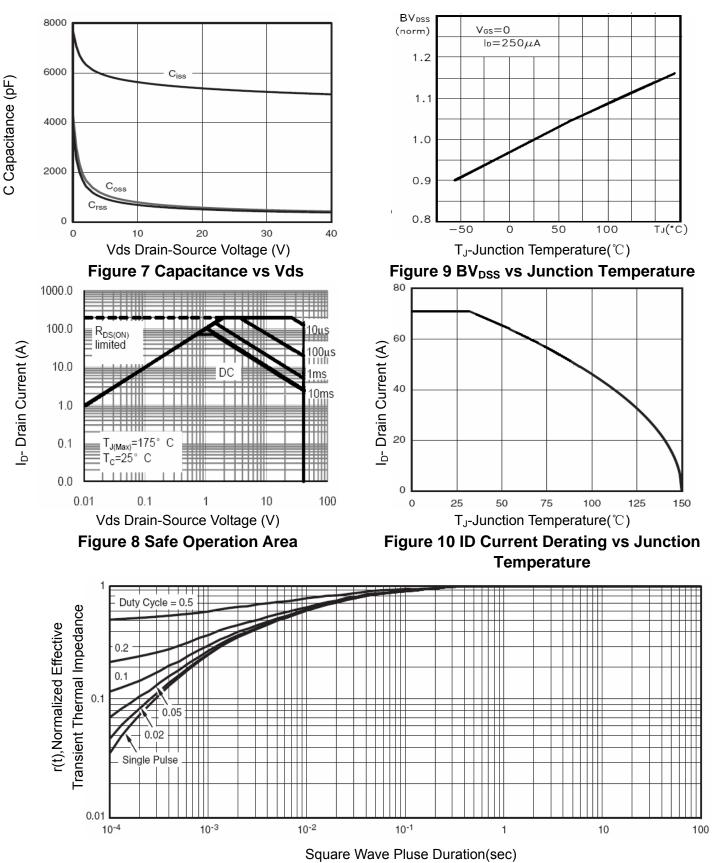


Figure 11 Normalized Maximum Transient Thermal Impedance

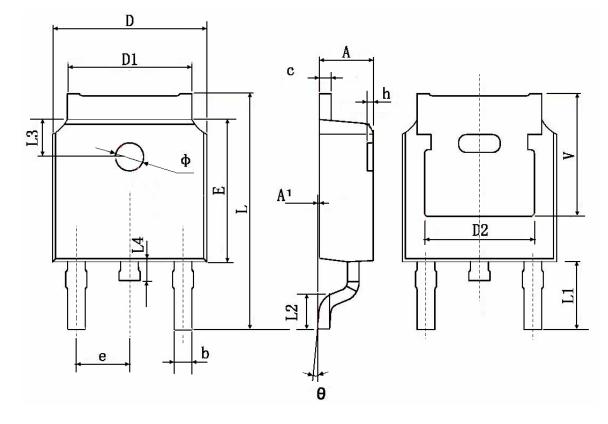


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NCE40P70K

TO-252 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063	TYP.	
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		







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